Decoupling of superconducting V by ultrathin Fe layers in V/Fe multilayers

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We report on a detailed study of superconducting critical temperatures $T_c$ and critical fields $H_{c2}$ of V/Fe multilayers. The thickness of the V layers ($d_V$) and Fe layers ($d_F$) as well as the total number of layers in the multilayer ($N$) were varied systematically. For $d_F > 0.6$ nm, at constant $d_V$, $T_c$ and the critical fields for parallel ($H_{c2\parallel}$) and perpendicular ($H_{c2\perp}$) orientation do not depend on either $d_F$ or $N$, and a two-dimensional ($2D$) temperature dependence for $H_{c2\parallel}$ without 3D-$2D$ crossover is observed for small values of $d_V$. The predicted oscillatory behavior of $T_c$ as a function of $d_F$ is not found. We conclude that the superconducting V layers are completely decoupled by only 0.6 nm Fe, in conflict with previous reports. Upon decreasing $d_V$ at constant $d_F$, a strong decrease of $T_c$ is found. This, together with the temperature dependence of $H_{c2\parallel}$ and $H_{c2\perp}$ for all samples can be described by existing theory.

I. INTRODUCTION

Because of the strong pair-breaking effect in ferromagnetic ($F$) layers, the superconducting ($S$) properties of a $S/F$ multilayer can be strongly influenced even by very thin $F$ layers. This was already known from experiments by Hauser, Theuerer, and Werthamer\(^1\) on bilayers with $S=$ Pb and $F=$ Fe, Ni, or Gd, and shown once more by Wong et al.\(^2,3\) on the V/Fe system. The latter experiments show that the critical temperature $T_c$ of $S/F$ multilayers and $F/S/F$ sandwiches drastically decreases with decreasing S-layer thickness $d_S$, even if the $F$ layer consists of a few atomic planes. The predominant pair-breaking mechanism in the $F$ layers is thought to be the polarization of the conduction electrons by the strong exchange field, and for not too thin Fe layers this will decouple the superconducting layers. Not quite clear, however, is whether coupling becomes possible when the $F$ layer is very thin (although ordered) and tunneling becomes possible. From the occurrence of a three-dimensional (3D) to two-dimensional (2D) crossover in $H_{c2\parallel}(T)$, Wong et al.\(^4\) concluded that this is indeed the case in V/Fe layers for Fe-layer thicknesses less than 1.3 nm (six atomic planes in their units).\(^5\) The possibility for this is the more interesting since such a coupling might be due to an exotic mechanism, which was recently investigated by Radović et al.\(^6,5\) and by Buzdin, Kupriyanov, and Vujčić.\(^6\) The order parameter would behave similar to the order parameter in a "$\pi$-contact" superconducting interferometer,\(^7\) in which the phase difference between two neighboring $S$ layers would no longer be 0, but could take a value between 0 and $\pi$. For an $S/F$ multilayer, the consequence is that $T_c$ oscillates as function of the thickness of the $F$ layer, $d_F$. An experimental indication for such behavior was found in V/Fe multilayers,\(^4\) but the data points are scarce and the existence of the $\pi$ phase has not been shown unambiguously.

Theoretical calculations also exist for the case of decoupled $S$ layers.\(^4\) A second motivation for the underlying investigation of V/Fe multilayers therefore was to make a systematic comparison between these calculations and the experiments.

Below, we describe two types of experiments. In the first we tried to observe $T_c$ oscillations in V/Fe multilayers by varying the Fe-layer thickness from 0.2 to 6.0 nm. The V-layer thicknesses are chosen in the range for which the $T_c$ oscillations are indicated by both the experimental results of Wong et al.\(^3\) and the theoretical calculations in Ref. 5. As we will show below, the multilayers have excellent compositional, magnetic, and superconducting characteristics. However, in these high-quality samples $T_c$ oscillations as function of $d_F$ were not observed, in conflict with results reported in Ref. 3. On the contrary, our results indicate that only 0.6-nm-thick Fe layers completely decouple the V layers. For $d_F > 0.6$ nm, both $T_c$, $H_{c2\parallel}$ and $H_{c2\perp}$ do not depend on $d_F$ or on the total number of layers in the multilayer, as expected if the V layers are completely decoupled. Also, if the individual V layers are thin enough, $H_{c2\parallel}(T)$ shows the well-known two-dimensional behavior $H_{c2\parallel} \propto \sqrt{1-T/T_c}$ in a wide temperature range. This has to arise from single V films, since the total sample thickness would not allow 2D...
behavior. In the second type of experiments, we investigated the behavior of $T_c$ and $H_{2d}(T)$ as function of V-layer thickness of multilayers with decoupled V layers. As expected, $T_c$ decreases drastically with decreasing $d_V$, in accordance with previously reported results. This is again an indication that our multilayers are of good quality. The data for $T_c$ vs $d_V$ and both the $H_{2d}$ and $H_{2e}$ vs $T$ curves for different $d_V$ can all be fitted to the theory mentioned above, where only one free adjustable parameter is needed.

II. EXPERIMENTAL DETAILS

Most series of multilayers were grown by dc magnetron sputtering (base pressure $5 \times 10^{-7}$ mbar). One series was grown by molecular-beam epitaxy (MBE) (base pressure $5 \times 10^{-16}$ mbar). In all cases the substrates were Si(001). The oxide layer was removed ex situ by dipping into a HF solution, and before deposition the surface was cleaned by glow discharge. During deposition, the substrates were kept at room temperature, while typical growth rates were 0.2 nm/s. X-ray diffraction was performed on one sputtered series and on the MBE-grown series. The high-angle data indicate that both V and Fe have bcc structure, but that the texture of the films is different for the two growth methods. The MBE-grown samples predominantly have (100) texture, while the sputtered samples showed (110) texture. The atomic plane distance is therefore 0.3 nm (V) and 0.29 nm (Fe) in the MBE case, but 0.21 nm (V) and 0.20 nm (Fe) for the sputtered samples. As we will see below, this apparently does not influence the superconducting or magnetic properties. At low angles, clear superlattice peaks were observed from which a period could be determined as a check on the growth rates.

Five different sets of multilayers were made with varying inner layer thicknesses and both V and Fe outer layers. We use the following notation: 44 nm V/3(0.6 nm Fe/44 nm V) means a sample with 44 nm V as the bottom layer, followed by three blocks of 0.6 nm Fe/44nm V. The top and bottom layers were always from the same material and equally thick (i.e., the multilayers were all completely symmetrical). Two sets had V outer layers and varying Fe-layer thicknesses. One of these was MBE grown with thicknesses 40 nm V/3($d_{Fe}$ Fe/40 nm V), and one was sputtered with thicknesses 44 nm V/3($d_{Fe}$ Fe/44 nm V), having $d_{Fe}$ = 0.6, 1.0, 1.6, 2.4, and 6.1 nm, as well as $d_{Fe}$ = 3.2 nm in the MBE-grown set.

Two sets had Fe outer layers, in which the inner Fe-layer thickness was varied [3 nm Fe/2(40 nm V/$d_{Fe}$ Fe)/3 nm $-d_{Fe}$ Fe with $d_{Fe}$ = 0.1, 0.2, 0.4, 0.6, 0.8, and 1.6 nm] or the number of blocks [3 nm Fe/N(40 nm V/1.0 nm Fe)/2 nm Fe, with $N = 2, 3, 4$, and 5]. In the final set, the V thickness was varied with constant Fe thickness, 5 nm Fe/2($d_V$ V/3.0 nm Fe)/2 nm Fe, with $d_V$ between 10 and 100 nm. In all cases the sample dimensions were 12 X 4 mm$^2$. The sets where the Fe-layer thickness was varied were used to investigate the decoupling of the V layers by the Fe layers. In the set with varying V-layer thickness, the V layers are decoupled. The superconducting properties of these multilayers strongly depend upon $d_V$, a result which can serve as a test for the model put forward in Ref. 5. For comparison, a MBE-grown V monolayer and a sputtered V monolayer of 150 nm thickness have also been measured.

In order to gain insight into the magnetic properties of our multilayers, we took magnetization curves at room temperature with a vibrating-sample magnetometer on all samples with V outer layers, i.e., MBE-grown 40 nm V/3($d_{Fe}$ Fe/40 nm V) and sputtered 44 nm V/3($d_{Fe}$ Fe/44 nm V), with $d_{Fe}$ variable. The field was applied parallel to the layers. Note that in order to extract the magnetic behavior of the thin inner Fe layers, it is necessary that the multilayers do not have protective Fe top and bottom layers. A typical magnetization curve for the sputtered sample 44 nm V/3(1.0 nm Fe/44 nm V) is shown in Fig. 1(a). Saturation of the magnetization was reached in fields below 0.13 T for all multilayers. The decrease of the magnetic signal for fields above the saturation field is due to the background, and it is only observable for multilayers having thin Fe layers. Figure 1(b) shows the saturation magnetization vs Fe-layer thickness for both sets of multilayers. The drawn straight line in the figure shows the magnetization assuming a bulk moment on the Fe atoms ($2.2_{\mu_B}$ corresponding to an internal field of 2.15 T) and no magnetic signal from the V layers. The data fall on a straight line with the same slope as for the bulk magnetization, as indicated by the dotted

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**FIG. 1.** (a) Magnetization vs applied field for the sputtered sample 44 nm V/3(1.0 nm Fe/44 nm V). (b) Saturation magnetization for samples 44 nm V/3($d_{Fe}$ Fe/44 nm V) (sputtered) (△) and 40 nm V/3($d_{Fe}$ Fe/40 nm V) (MBE grown) (○). The solid line is expected for an Fe atom bulk moment of $2.2_{\mu_B}$. The dotted line is a guide to the eye, indicating 0.1 nm magnetically dead Fe material on the interfaces.
line. However, the x axis is intercepted at 2 Å. Since the effective moment on Fe atoms decreases drastically with increasing V concentration in V/Fe alloys, this result indicates that either a dead layer exists of about 1 Å when the interface is perfectly sharp or mixing occurs over no more than one atomic plane. From these results we infer that the Fe atoms have a well-defined moment, even in very thin Fe layers.

The superconducting properties \( T_c, H_{c2}(T) \), and \( H_{c1}(T) \) were measured resistively in a standard four-terminal configuration and defined at the midpoint of the superconducting-normal transition. \( H_{c2} \) was measured by sweeping the field at constant temperature. The samples showed good superconducting properties, with \( \Delta T_c \) as defined by a 10–90% transition width typically less than 20 mK and very sharp transitions in the field.

III. RESULTS AND DISCUSSION

A. Decoupling by ultrathin Fe layers

In Fig. 2, \( T_c \)'s are shown for all sets of multilayers where the Fe-layer thickness was varied, together with the results for the 150-nm-thick V monolayers and one sample from another set with the same V thickness [5 nm Fe/2(40 nm V/3.0 nm Fe)/2 nm Fe]. The well-known effect of \( T_c \) reduction by even very thin Fe layers is reproduced. For \( d_{Fe} \geq 0.6 \) nm, \( T_c \) is independent of \( d_{Fe} \), indicating that Fe layers with \( d_{Fe} = 0.6 \) nm already completely decouple the V layers.

For \( d_{Fe} \leq 0.4 \) nm, \( T_c \) is strongly influenced by \( d_{Fe} \). This may be caused both by a decrease of the moment on the Fe atoms in these very thin Fe layers and by the fact that the V layers are not completely decoupled anymore. Note that a hypothetical multilayer in the set 3 nm Fe/2(40 nm V/\( d_{Fe} \)/Fe/3 nm Fe -- \( d_{Fe} \)) Fe with \( d_{Fe} = 0.0 \) nm should not be compared to the 150-nm-thick monolayers, but rather to one 80-nm-thick V layer sandwiched between two Fe layers, which already has a lower \( T_c \) than bulk V. Therefore \( T_c \) for sample 5 nm Fe/2(85 nm V/3.0 nm Fe)/2 nm Fe is also shown. The difference in \( T_c \) for the sputtered multilayers from the sets 44 nm V/3(\( d_{Fe} \)/Fe/44 nm V) and 3 nm Fe/2(40 nm V/\( d_{Fe} \)/Fe/3 nm -- \( d_{Fe} \))Fe is mainly caused by the difference in top and bottom layers. When the outer layers consist of Fe, all V layers are identical. Outer layers of V, however, will not be identical to inside V layers, since they have Fe on one side only. The depression of the order parameter due to the S/F interface, which will be discussed in more detail later, will therefore be less in the outer layers, leading to a higher \( T_c \). If the Fe layers decouple the V layers, this is the \( T_c \) measured and shown in Fig. 2.

Concentrating on the multilayers in the set 3 nm Fe/N(40 nm V/1.0 nm Fe)/2 nm Fe, we see that varying the number of layers in a multilayer does not influence \( T_c \), even though the inner Fe layers are only 1 nm thick. This is as expected when only 0.6 nm of Fe decouples the V layers completely. These results are also interesting with respect to theoretical calculations by Kulik, which indicate that the \( T_c \) of a multilayer can depend on the number of layers if a weak electron correlation between the S layers is present. This electron correlation is different from electron transfer by Josephson coupling or a proximity effect. Experimentally, \( T_c \) dependence on number of layers was observed in Ag-In and Ag-Sn multilayers. If the approximations in Ref. 9 are appropriate, our result that the number of layers does not influence \( T_c \) is further evidence that the V layers are completely decoupled.

To check this main finding, we also measured the critical fields. In Fig. 3 we show \( H_{c2} \) vs \( T \) for several samples with inner Fe layers of 0.6 nm and, for comparison, for some samples with thicker Fe layers. Concentrating on the multilayers with \( d_{Fe} = 0.6 \) nm, we observe that \( H_{c2} \) for all three samples behaves in agreement with the ex-

**FIG. 2.** \( T_c \) vs \( d_{Fe} \) for different multilayers; with V outer layers: 44 nm V/3(\( d_{Fe} \)/Fe/44 nm V) (□) and 40 nm V/3(\( d_{Fe} \)/Fe/40 nm V) (MBE grown) (●); with Fe outer layers: 3 nm Fe/2(40 nm V/\( d_{Fe} \)/Fe/3 nm -- \( d_{Fe} \)) Fe (●), supplemented with 5 nm Fe/2(40 nm V/3.0 nm Fe)/2 nm Fe with varying number of blocks: 3 nm Fe/N(40 nm V/1.0 nm Fe)/2 nm Fe with \( N = 2 \) (△), \( N = 3 \) (▲), \( N = 4 \) (+), \( N = 5 \) (∆). Also shown are monolayers of 150 nm, sputtered (□) and MBE grown (○), and multilayer 5 nm Fe/2(85 nm V/3.0 nm Fe)/2 nm Fe (◇).

**FIG. 3.** \( H_{c2} \) for multilayers with different outer layers and different \( d_{Fe} \): 44 nm V/3(0.6 nm Fe/44 nm V) (▼) and 44 nm V/3(2.4 nm Fe/44 nm V) (▼); 40 nm V/3(0.6 nm Fe/40 nm V) (MBE grown) (●) and 40 nm V/3(2.4 nm Fe/40 nm V) (MBE grown) (○); 3 nm Fe/2(40 nm V/0.6 nm Fe)/2.4 nm Fe (■) and 3 nm Fe/2(40 nm V/1.6 nm Fe)/1.4 nm Fe (●). All solid symbols represent samples with inner Fe layers of 0.6 nm.
expectation for a two-dimensional thin film in a parallel field,

$$H_{c2}(T) = H_{c2}(0)(1 - T/T_c)^{1/2}. \tag{1}$$

This is especially clear from the inset in Fig. 4, where $H_{c2}(T)/(1 - T/T_c)^{1/2}$ is plotted. This 2D behavior is observed up to $T/T_c = 1$; i.e., a transition from 2D to 3D behavior is not observed. This is again a strong indication that V layers are decoupled, since the total sample thicknesses are too large for 2D behavior to occur over more than a fraction of the temperature range if V layers were not decoupled. It should be mentioned that in Ref. 3 clear 3D to 2D transitions were observed in V/Fe multilayers with Fe layers of 0.6 nm, indicating that in those samples the Fe layers did not decouple the V layers completely. Comparing each of the three samples with a sample from the same set but with thicker Fe-layer thickness, we see (inset of Fig. 4) that values for $H_{c2}(0)$ for samples within the same set differ less than 12%, with no systematics regarding Fe-layer thickness. $H_{c2}(0)$ does depend upon the material of top and bottom layers, being larger for samples with V on top and bottom. In the same way as discussed for $T_c$, this means that $H_{c2}$ is larger for the outer V layers. It is interesting to note that $H_{c2}(T)$ of these outer layers still shows the square-root behavior expected for thin films. Single V films of 40 nm would show 3D behavior at low temperature, since this thickness is larger than twice the zero-temperature coherence length of 13.9 nm (see below).

In Ginzburg-Landau (GL) theory for a single thin film in vacuum, $H_{c2}(0)$ as defined in Eq. (1) can be written as

$$H_{c2}(0) = \phi_0 \sqrt{12/(2\pi \xi(0)d)},$$

with $\phi_0$ the flux quantum, $\xi(0)$ the zero-temperature GL coherence length, and $d$ the thickness of the film. In the next section, we will show that, as a result of the different boundary conditions, this factor is different for $F/S/F$ sandwiches or $S/F$ bilayers. It depends upon the $F$ material and does not have a simple functional form with respect to $d_F$. Nevertheless, the angular dependence of $H_{c2}(\theta)$, with $\theta$ the angle between the layers and the field, is still correctly described by the Tinkham expression for a thin film in vacuum,

$$\frac{H_{c2}(\theta) \sin(\theta)}{H_{c21}} + \frac{H_{c2}(\theta) \cos(\theta)}{H_{c21}} = 1. \tag{2}$$

This is seen from Fig. 4, where $H_{c2}(\theta)$ is plotted for one sample with 0.6-nm-thick Fe layers, measured at $T = 2.5$ K ($t = 0.66$). The line is a fit to Eq. (2), and the agreement is remarkably good.

Not only $H_{c2}$ but also $H_{c21}$ for the multilayers should be independent of $d_F$ if V layers are decoupled. In Fig. 5, $H_{c21}$ is plotted versus reduced temperature for the sputtered samples for which $H_{c2}$ was shown in Fig. 3. Also shown is the result for a sputtered V monolayer with thickness 150 nm. All measurements show a linear $T$ dependence near $T_c$. It is indeed observed that the Fe-layer thickness does not influence the $H_{c2}$ curves. The difference in $H_{c21}$ at any $T$ is less than 8% for multilayers from the same set.

The temperature dependence of $H_{c21}$ near $T_c$ is, in GL theory, given by

$$H_{c21}(T) = \frac{\phi_0}{2\pi \xi(0)^2}(1 - T/T_c). \tag{3}$$

Then, for the slope $S$ of $H_{c21}$ with the reduced temperature $t = T/T_c$, one has

$$S = -\frac{\partial H_{c21}}{\partial t}igg|_{t=1} = \frac{\phi_0}{2\pi \xi(0)^2}. \tag{4}$$

The values for $S$ in Fig. 5 are clearly not all the same, even though the V layers have the same $\xi(0)$. Again, this is mainly due to the different material of top and bottom layers. For the multilayer with V as outside layers, the behavior of $H_{c2}$ is again completely determined by only the outside layers. The value for $S$ for these multilayers is apparently larger than for multilayers with Fe as out-

![FIG. 4. Angular dependence of the critical field for sample 44 nm V/3(0.6 nm Fe/44 nm V) at $T = 2.5$ K ($t = 0.66$). The line is a fit to the 2D expression [Eq. (2)]. The inset shows $H_{c21}(t)$ divided by $(1 - t)^{1/2}$ vs $t$ for the data of Fig. 3. Symbols are the same as in Fig. 3.](image)

![FIG. 5. $H_{c21}$ for multilayers with different outer layers and different $d_F$: 3 nm Fe/240 nm V/0.6 nm Fe/2.4 nm Fe (■) and 3 nm Fe/240 nm V/1.6 nm Fe/1.4 nm Fe (□); 44 nm V/3(0.6 nm Fe/44 nm V) (▼) and 44 nm V/3(2.4 nm Fe/44 nm V) (▼); also shown is the 150-nm-thick sputtered monolayer (+).](image)
side layers, although still smaller than for single thin films. This shows that Eq. (4) cannot be used anymore to determine $\xi(0)$ for a multilayer. In the next section, we will see that also the thickness of $d_V$ influences the slope $S$. For the monolayer, Eq. (4) is of course valid and gives $\xi(0)=13.9$ nm. This value will also be used for the $V$ in the multilayers.

Concluding this section, in Fig. 6 we show $H_{c2\parallel}$ and $H_{c2\perp}$ for two samples with a different number of blocks, one with two $V$ layers and one with four $V$ layers, all of the same thickness and sandwiched between Fe layers of 1.0 nm thickness. Clearly and as expected, when $V$ layers are decoupled, the behavior for both multilayers is exactly the same.

B. Critical temperatures and fields: Comparison with theory

In the preceding section, we focused on the decoupling of $V$ layers by the Fe layers. In this section we will study the influence of the thickness of the $V$ layers on the superconducting properties of multilayers with decoupled $V$ layers. These systems have been studied theoretically both in Ginzburg-Landau theory\textsuperscript{11} and in a microscopic approach.\textsuperscript{4} Especially the last is suitable for comparison with our results, since in that paper the results of the model are compared with the experimental data of Ref. 3 on $V$/Fe multilayers. Reasonable agreement is obtained, but only if one assumes a rather strong dependence of superconducting parameters of the individual $V$ layers upon their thickness, which does not seem justified. Also, the data for the perpendicular critical fields are very scarce. To make a more systematical comparison, we therefore measured $T_c$ and $H_{c2}(T)$, in both perpendicular and parallel orientations for samples with constant Fe thickness and varying $V$ thickness, 5 nm Fe/2$\left(d_V V/3.0$ nm Fe)/2 nm Fe, with $d_V=10, 15, 20, 25, 32.5, 40, 55, 70, 85,$ and 100 nm. Since these samples all have Fe as top and bottom layers, all $V$ layers within the multilayer are identical. In Fig. 7 the results for $T_c$ are displayed. $T_c$ decreases strongly with decreasing $V$-layer thickness, as was also found in Refs. 1 and 3. The samples with $d_V$ smaller than 32.5 nm were measured in a dilution refrigerator, but no superconductivity was found for temperatures down to 50 mK. From this we infer the critical $V$-layer thickness for superconductivity to be approximately 28 nm. Looking at the sample with $d_V=100$ nm, we note that $T_c$ is still lower than for bulk Fe, even though $d_V$ is much larger than $\xi(0) (=13.9$ nm) for bulk Fe. Below, we will show that these results are correctly described by the model proposed by Radović \textit{et al.} in Ref. 4.

At this point we want to come back on the $T_c$ oscillations with varying Fe-layer thickness as discussed in the previous section. We have also tried to observe these in multilayers with $V$ inner layers of 25 nm, separated by Fe layers with variable thickness and with 5-nm Fe top and bottom layers. The inner Fe layers ranged between 0.2 and 8 nm. No superconductivity was found for $T>1.4$ K when $d_{Fe} \geq 0.6$ nm, in accordance with the results above, and also in this set the $T_c$ oscillations (or in this case the reentrance of superconductivity) could not be observed.

Figure 8 shows the $H_{c2\parallel}$ vs $T$ curves for multilayers 5 nm Fe/2$\left(d_V V/3.0$ nm Fe)/2 nm Fe, with $d_V=40, 55,$ and 85 nm together with $H_{c2\parallel}$ for the 150-nm sputtered monolayer. Close to $T_c$ all multilayers show the 2D behavior as given by Eq. (1). This is indicated by the dashed curves in the figure. For multilayers with $d_V=40$ and 55 nm, this behavior exists in the whole measurable temperature range. The multilayer with $d_V=85$ nm shows a crossover from 2D behavior at temperatures near $T_c$ to 3D behavior of the single $V$ film at low $T$. Whether this 2D to 3D transition also takes place for the sample with $d_V=55$ nm is difficult to state, since the 3D and 2D behaviors for this sample at low temperatures practically coincide. The 2D to 3D transition is observed for all
multilayers with \( d_v \geq 70 \) nm (see the inset of Fig. 8), which means that at low temperatures all \( V \) layers with \( d_v \geq 70 \) nm behave as 3D thick \( V \) monolayers. Single \( V \) layers in parallel orientation would show a higher critical field than in perpendicular orientation as a result of surface superconductivity, but this (or rather “interface” superconductivity) does not occur in our multilayers, since, at low \( T_c \), \( H_{c2}\) for the multilayers coincides with \( H_{c2}\) of the single \( V \) film. We come back to this point below. Note that the 2D to 3D transition in the multilayers is a property of a single \( V \) film.

In Fig. 9 we show the \( H_{c2}\) vs \( T \) curves for the samples for which \( H_{c2}\) was shown in Fig. 8, together with the result for the sputtered \( V \) monolayer. All measurements show linear behavior near \( T_c \), but also the slopes \( \partial H_{c2} / \partial T \) differ by less than 15% for all samples in the set and are equal to the slope of the monolayer. The Ginzburg-Landau expression for \( H_{c2} \) [Eq. (4)] implies that the slope \( \partial H_{c2} / \partial T \) depends upon the product \( \langle g(0)^2 T_c \rangle^{-1} \) and thus that the slope should increase with decreasing \( T_c \), assuming that \( g(0) \) does not depend on the layer thickness \( d_v \). We will see below that the constant slopes are indeed predicted by the model of Ref. 4. Here we only want to note again that for \( F/S/F \) multilayers or sandwiches, the GL expression of Eq. (4) clearly cannot be used to deduce \( g(0) \) from \( H_{c2} \).

Next we show that our experimental results are well described by the model put forward in Ref. 4. We will give a brief sketch of the derivation of the basic equations relating the superconducting properties \( T_c \), \( H_{c2} \), and \( H_{c2} \) to the \( V \)-layer thickness. The reader is referred to Ref. 4 and references cited therein for the theoretical details. The model is based on the Usadel equations, and it assumes that all \( S \) layers are decoupled. The phase transition at \( H_{c2} \) is taken to be of second order, so that the Gorkov’s Green’s function describing the condensate of pairs, \( F(r, \omega) \) with \( \omega \) a Matsubara frequency, is described by a linear equation. \( F(r, \omega) \) is connected to the pair potential \( \Delta = \Delta(r) \) by the self-consistency condition. Using the ansatz that separation of variables can be used and that the space-dependent part of \( F, F(r) \), equals \( \Delta(r) \), the equations listed below are derived.\(^\text{12}\) Since the \( S \) layers in the multilayer are decoupled, one only needs to consider one \( S \) layer embedded between two \( F \) layers to find the multilayer behavior. The coordinate system is chosen so that the interfaces are parallel to the \( yz \) plane and the center of the \( S \) layer is at \( x = 0 \).

For the superconducting material, one has

\[
\Pi^2 F_s = -k_S^2 F_s ,
\]

where \( \Pi = \nabla + 2\pi i A / \phi_0 \) is the gauge-invariant gradient with \( A \) the vector potential. The eigenvalue \( k_S(t) \), with \( t = T / T_c \) and \( T_c \) the bulk transition temperature for the \( S \) material, is related to an effective pair-breaking parameter \( \rho(t) \) by

\[
k_S^2 = 2 \rho / \delta_S^3 .
\]

Here the \( S \) material parameter \( \delta_S \) is given by

\[
\delta_S = (\hbar D_S / 2\pi k_B T_c) \chi_S^{1/2} ,
\]

with \( D_S \) the diffusion coefficient. The GL coherence length at \( T = 0, \xi(0) \), is related to \( \delta_S \) by \( \delta_S = 2\xi(0) / \pi \). The pair-breaking parameter \( \rho(t) \) is related to \( t \) by

\[
\ln(t) = \psi(1/2) - \text{Re} \psi(1/2 + \rho/t) ,
\]

with \( \Psi \) the digamma function and \( \text{Re} \) meaning that the real part should be taken.

In the \( F \) layers, the predominant pair-breaking mechanism is assumed to be the strong exchange-field effect which polarizes the spins in the Cooper pairs, leading to
the destruction of superconductivity. Therefore the critical temperature for the $F$ material is taken to be zero, but in a multilayer near the interface $F_F$ is nonzero because of the proximity from the $S$ layers. Assuming that the exchange energy $I_0$ is much larger than $k_T T_{SC}$, the other characteristic energy involved, and that the pair-breaking effect of any real externally applied magnetic field can always be neglected in comparison with the pair breaking of the exchange field, one has an exponential decay for $F_F$ in the layers,

$$F_F(x) = C_1 \exp(-k_F|x|),$$  \hspace{1cm} (9)

with $C_1$ an arbitrary constant. The characteristic inverse length $k_F$ is independent of $T$ and is given by

$$k_F = 2(1+i)/\xi_F,$$  \hspace{1cm} (10)

with

$$\xi_F = (4\hbar D_F/I_0)^{1/2}$$  \hspace{1cm} (11)

and $D_F$ the diffusion coefficient in the $F$ material. Note that the decay length of $F$ in the $F$ layers depends upon $I_0$ and that $k_F$ is a complex quantity, which stems from the fact that the exchange field can be thought to act only on the spin-dependent part of the electrons.

The solutions for $F_F$ and $F_S$ are subject to the generalized de Gennes–Werthamer boundary condition at the $S/F$ interface,

$$\frac{d}{dx} \ln F_S = \eta \frac{d}{dx} \ln F_F \Bigg|_{x=\pm d_S/2},$$  \hspace{1cm} (12)

with $d_S$ the thickness of the $S$ layer. The parameter $\eta$ characterizes the interfaces; e.g., in the dirty limit for specular scattering, $\eta$ is the ratio of the normal-state conductivities $\sigma_F$ and $\sigma_S$, $\eta = \sigma_F/\sigma_S$. From symmetry, $F_S$ should be symmetrical in $x = 0$.

The above set of equations now suffices to calculate $T_c$ for a multilayer as function of $d_S$. At $T_c (H = 0)$, Eq. (5) can be solved exactly, $F_S = C_2 \cos(k_{3D} r)$, with $k_{3D}$ the value of $k_S$ at $T_c$. Inserting this solution together with (9) in (12) results in

$$\varphi_0 \tan(\varphi_0) = (1+i) \frac{d_S/\xi_S}{\epsilon},$$  \hspace{1cm} (13)

with $\varphi_0 = k_{3D} d_S/2$ and $\epsilon = \xi_F/\eta \xi_S$. For given $\epsilon$ and $d_S/\xi_S$, this equation can be solved, giving $k_{3D}$, and with Eq. (6) it yields the effective pair-breaking parameter $\rho$ at $T_c$. Inserting $\rho$ in Eq. (8) then gives $T_c$ for the multilayer.

Note that, since $\xi_F, d_S$, and $T_{SC}$ are known, $\epsilon$ is the only free parameter left.

To compare $T_c$ for our multilayers with the model, we used the experimental results of the sputtered monolayer, $T_{SC} = 5.1 \text{ K}$ and $\xi_S = 8.8 \text{ nm}$ \cite{[22]} \(= 2\xi(0)/\pi\), with $\xi(0) = 13.9 \text{ nm}$). Taking $\epsilon = 5.1$ yields the solid line in Fig. 7. The agreement between experiment and theory is seen to be very satisfactory, and the critical thickness for superconductivity, $\approx 28 \text{ nm}$, is nicely reproduced. The predicted $T_c$ vs $d_V$ behavior depends strongly on $\epsilon$, giving a rather small interval for $\epsilon$ values describing the experiments, $\epsilon = 5.1 \pm 0.2$. Wong and Ketterson\cite{[23]} calculated $T_c$ for a $S$ layer sandwiched between $F$ layers in GL theory, assuming $|\psi_{GL}|^2 \propto \cos(kx)$ for the GL order parameter $|\psi_{GL}|^2$, which is the same space dependence as for $F_S$ discussed above. Under the assumption that the GL order parameter $|\psi_{GL}|^2$ is zero in the magnetic layers and taking the boundary condition that $|\psi_{GL}|^2 = 0$ at the interfaces, they find that $T_{cS} - T_c \approx 1/d_S^2$. In the inset of Fig. 7, we show that our results are also nicely described by this phenomenological relationship, and the prediction for the critical thickness of 30 nm (see the inset for the construction) is in good agreement with the experimental results.

If the $S$ layers are thin enough to exclude vortices, the critical field parallel to the layers, $H_{c2}(T)$, can be calculated assuming that the nucleation of superconductivity starts in the middle of the film. Under the condition that $2\pi H_{c2} d_S^2/(4\Phi_0) < 1$, it was shown in Ref. 4 that the final effect of the presence of the field $H_{c2}$ on the effective pair-breaking parameter $\rho(t)$ can be approximated by

$$\rho(t) = \rho(t_c) + \frac{g(\varphi_0)}{24} \left[ \frac{2\pi H_{c2} \Phi_0}{\varphi_0} \right]^2 d_S^2 \xi_S^2.$$  \hspace{1cm} (14)

Here $\rho(t_c)$ is the pair-breaking parameter at $T_c$. The numerical factor $g(\varphi_0)$ is given by

$$g(\varphi_0) = 1 - \frac{3}{2\varphi_0^2} + \frac{3 + 2\varphi_0 \tan(\varphi_0)}{\varphi_0^3 + \varphi_0 \tan(\varphi_0) + (\varphi_0 \tan(\varphi_0))^2}.$$  \hspace{1cm} (15)

It should be noted that once $\epsilon$ [and thus $\rho(t_c)$ for given $d_S$] has been obtained from the fit of $T_c$ vs $d_S$, Eq. (14) does not contain any free adjustable parameter anymore. For given $t$, $\rho(t)$ can be calculated with Eq. (8), and equating to Eq. (14) yields $H_{c2}(t)$. In Fig. 8 we compare our data for $H_{c2}$ with Eq. (14) using $\epsilon = 5.1$ as obtained from the $T_c$ vs $d_S$ data. The agreement between data and theory is again very satisfactory in the regime where the multilayers behave as 2D superconductors, since both the $T$ dependence and the magnitude of $H_{c2}$ are correctly described. Since in Eq. (14) the $S$ layers are assumed to be 2D, the 2D to 3D crossover for $d_V = 85 \text{ nm}$ cannot be reproduced. The model sketched above was recently extended for $F/S/F$ triple layers with $S$ layers of arbitrary thickness.\cite{[24]} We will not reproduce those calculations here, but 2D to 3D crossovers are predicted above a certain thickness $d_{SCR}$ of the $S$ layers. This thickness $d_{SCR}$ would be equal to $1.8 \xi(T)$ for a thin film in vacuum, but is larger for the $F/S/F$ case and depends on the value of $\epsilon$. If $\epsilon$ is not too small, it is even possible that $H_{c2}$ is enhanced over $H_{c2}$ in a manner similar to the nucleation of surface superconductivity. Enhancement would not take place for $\epsilon = 5.1$, in agreement with the observations that $H_{c2}$ for multilayers with $d_V \geq 70 \text{ nm}$ coincides with
$H_{c2}$ for the monolayer at low temperatures (see the inset of Fig. 8). Also, $\varepsilon = 5.1$ corresponds to $d_{SC} \approx 4\xi_S$, so that below $d_v \approx 35$ nm no crossover can occur down to $T = 0$, in good qualitative agreement with the 2D behavior for the multilayer with $d_v = 40$ nm in the whole measured temperature range.

For perpendicular fields the expression for the pair-breaking parameter $\rho(t)$ becomes

$$\rho(t) = \rho(t_c) + \frac{\pi H_{c2}}{\phi_0} \xi_F^2 . \tag{16}$$

Again, it should be noted that for given $\varepsilon$ this expression does not contain any free parameters. In Fig. 9 it is shown that the experimental data are well described by the model. The linear $T$ dependence of $H_{c2}$ close to $T_c$ is well reproduced, as well as the independence on $d_v$ of the slope of $H_{c2}$ for $T$ near $T_c$.

The results above show that the model proposed by Radović et al.\textsuperscript{4} describes all our results satisfactorily. The only fitting parameter $\varepsilon$ is found to be 5.1. It is now interesting to see the implications for the characteristic decay length $\xi_F$ of the Green’s function $F_F$ in the $F$ material [Eqs. (9)–(11)]. Our results showed that only 0.6-nm Fe layers completely decouple the V layers. Assuming that the V bands are not polarized and that the exponential decay of the $F$ function therefore starts at the physical interfaces, this implies that $\xi_F$ is of the order of 0.6 nm. With $\xi_F = \eta \xi_S = \eta 44.9$ nm, the interface parameter $\eta$ should be less than 0.013. It is difficult to comment on this value since much is unknown about the interface scattering. The measured values for the specific resistivities at $T = 3.5$ K of single films of Fe and V are 6.2 and 6.9 $\mu\Omega$ cm, respectively, with a ratio $\sigma_F / \sigma_S$ of the order of 1. On the other hand, these values are mainly determined by grain-boundary scattering in the plane of the film, which is not relevant for $\eta$. For single-crystalline material, the resistances are much lower, 0.05 $\mu\Omega$ cm for Fe and 2.5 $\mu\Omega$ cm for V and the ratio $\sigma_F / \sigma_S$ is increased to 50. Most probably, $\eta$ is for a large part determined by the change of bond structure at the interface and not easily accessible by experiment, although resistance measurements perpendicular to the layers might give more information on this. Moreover, since a part of the conduction electrons in Fe is believed to consist of highly polarized itinerant $d$-like electrons,\textsuperscript{14} the scattering may be strongly spin dependent. The low value for $\eta$ may therefore well be caused by different spin channels, rather than by interface roughness or by different overall conductivity.

The other important parameter entering the model is the exchange energy $I_0$. Estimating $I_0$ from the fitting procedure above again requires rough assumptions. Again, taking $\xi_F = 0.6$ nm, we can try to make an estimation for $I_0 = 4\pi D_F / \xi_F^2$. The diffusion coefficient $D_F = \nu_F / 3$, with $\nu_F$ the Fermi velocity, for our thin Fe layers is not exactly known. Even if we take the smallest possible value for $l$, namely, the layer thickness of 0.6 nm, and using the typical Fermi velocity for Fe, $\nu_F = 2 \times 10^6$ m/s, this yields $I_0 = 4.6 \times 10^{-19} J \approx 3.0$ eV. Note that if $l$ is taken to be larger than 0.6 nm, $I_0$ would even increase. The value for $I_0$ would not be unreasonable if it could be compared to half the exchange splitting of the itinerant $d$ electrons, estimated at about 1 eV,\textsuperscript{15} instead of to the $s$-$d$ exchange energy which is typically a few tenths of an eV. Also, the strong spin-dependent scattering at the nonmagnetic interface would naturally lead to the assumed restriction of the mean free path by the layer thickness.

All parameter values estimated above indicate an important role of the Fe itinerant $d$ electrons. However, since both $\eta$ would increase and $I_0$ decrease with increasing $\xi_F$, we should closely scrutinize the estimate for $\xi_F$ which was obtained by neglecting the possible polarization of electrons in the V layers due to the Fe layers. If polarization were present, the result would be that the exponential decrease of superconductivity would already start deep inside the V layers, instead of starting at the physical Fe/V interface as assumed above. The effective separation between superconducting V material would be larger than just the Fe layer thickness, and a (much) larger decay length for superconductivity than 0.6 nm would follow. Trying to incorporate this idea in the model, we tried to describe the experiments assuming a roughly estimated thickness of 4 nm polarized V on each interface, so that the effective V-layer thickness $d_v$ is 8 nm less than the nominal sputtered thickness. From fitting $T_c$ vs $d_v$ data, we then obtain $\varepsilon = 7$, and both $T_c$ vs $d_v$ and $H_{c2}(T)$ curves are well described by the model. The predicted $H_{c2}$ values are, however, too high, about 25% for the thinnest sample with $d_v = 40$ nm, and so within the assumptions of the model, this picture is not capable of describing all the data consistently.

Finally, we would like to remark here that even though all the data on our V/Fe multilayers can be described with the model of Radović et al., we performed the same type of measurements on V/F multilayers with for $F$ different types of thick ferromagnetic layers, especially Ni and Co, which will be the subject of a separate paper. For all these multilayers, $T_c$ with varying $d_v$ can be accurately fitted, but the critical field data are not as well described as in the V/Fe case.

IV. CONCLUSION

To summarize, we have shown that for well-defined V/Fe multilayers the superconductivity in adjacent V layers is decoupled by only 0.6-nm-thick Fe layers. This is concluded from the independence of the superconducting properties $T_c$, $H_{c2}$, and $H_{c2}$ on $d_F \geq 0.6$ nm, as well as from the 2D temperature dependence of $H_{c2}$ for thick multilayers with thin V layers. A “$\pi$-contact” superconducting ground state does not exist in our multilayers, in contrast with suggestive results on V/Fe multilayers by Wong et al.\textsuperscript{1} We have also shown that $T_c$ and both $H_{c2}$ and $H_{c2}$ can be consistently and very nicely described by...
the model of Radović et al., using only one adjustable parameter. The manner in which the effect of magnetism is introduced in the problem appears to be a correct approach. The values found for the interface characterization parameter $\eta$ and the exchange energy $I_0$ indicate that the itinerant $d$ electrons of Fe play an important role in the destruction of the Cooper pairs. A better microscopic understanding especially of the spin dependence of the scattering at the interfaces is still needed.

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12. This ansatz yields an approximate solution for the Usadel equations and amounts to a generalization of the de Gennes–Werthamer approach. An exact solution could lead to qualitative different results, especially when the $S$ layers in the multilayer are not completely decoupled, but for decoupled, not too thin $S$ layers sandwiched between strong ferromagnetic material, the two approaches lead to qualitatively the same results. See Ref. 5 and Z. Radović, M. L. Ledvij, and L. Dobrosavljević-Grujić, Solid State Commun. 80, 43 (1991).
15. For this estimate we use $k_f^2 = 11$ nm$^{-1}$, $k_d^2 = 4$ nm$^{-1}$ from Ref. 14 and an effective mass $m^* = 2$; see M. B. Stearns, Phys. Rev. B 8, 4383 (1973). The full exchange splitting from these numbers is 2 eV. In Ref. 4, the full splitting is implicitly defined as $2I_0$, so our $I_0$ is half the splitting.